

SLOS531B - MAY 2007 - REVISED OCTOBER 201

3-Channel RGBHV Video Buffer with I²C™ Control, 2:1 Input Mux, Monitor Pass-Through, and Selectable Input Bias Modes

Check for Samples: THS7347

FEATURES

- 3-Video Amplifiers for CVBS, S-Video, EDTV, HDTV Y'P'_BP'_R, G'B'R', and R'G'B' Video
- H/V Sync Paths with Adjustable Schmitt Trigger
- 2:1 Input Mux
- I²C Control of All Functions on Each Channel
- Unity-Gain Buffer Path for ADC Buffering:
 - 500-MHz Bandwidth, 1200-V/µs Slew Rate
- Monitor Pass-Through Function:
 - 500-MHz Bandwidth, 1300-V/µs Slew Rate
 - 6-dB Gain with SAG Correction Capable
 - High Output Impedance in Disable State
- Selectable Input Bias Modes:
 - AC-Coupled with Sync-Tip Clamp
 - AC-Coupled with Bias
 - DC-Coupled with Offset Shift
 - DC-Coupled
- +2.7-V to +5-V Single-Supply Operation
- Total Power Consumption: 265 mW at 3.3 V
- Disable Function Reduces Current to 0.1 µA
- Rail-to-Rail Output:
 - Output Swings Within 0.1 V of the Rails,
 Allowing AC- or DC-Output Coupling
- · Lead-free, RoHS TQFP Package

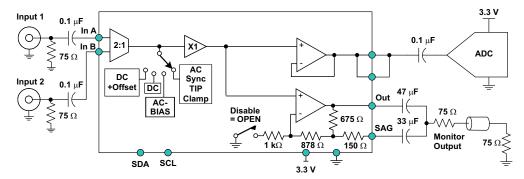
APPLICATIONS

- Projectors
- Professional Video Systems
- LCD/ DLP[®]/LOCS Input Buffering

DESCRIPTION

Fabricated using the revolutionary complimentary silicon-germanium (SiGe) BiCom3 process, the THS7347 is a low-power, single-supply 2.7-V to 5-V 3-channel integrated video buffer with horizontal (H) and vertical (V) sync signal paths. It incorporates a 500-MHz bandwidth, 1200-V/µs unity-gain buffer ideal for driving analog-to-digital converters (ADCs) and video decoders. In parallel with the unity-gain buffer, a monitor pass-through path allows for passing the input signal on to other systems. This path has a 6-dB gain, 500-MHz bandwidth, 1300-V/µs slew rate, SAG correction capability, and high output impedance while disabled.

Each channel of the THS7347 is individually I²C-configurable for all functions, including controlling the 2:1 input mux. Its rail-to-rail output stage allows for both ac- and dc-coupling applications.



3.3 V Single-Supply Projector Input System with Monitor Pass-Through (One of Three R'G'B' Channels Shown)

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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DESCRIPTION, CONTINUED

As part of the THS7347 flexibility, the device input can be selected for ac- or dc-coupled inputs. The ac-coupled modes include a sync-tip clamp option for CVBS/Y'/G'B'R' with sync or a fixed bias for the C'/P'_B/P'_R/R'G'B' channels without sync. The dc input options include a dc input or a dc+Offset shift to allow for a full sync dynamic range at the output with 0-V input.

The THS7347 is available in a lead-free, RoHS-compliant TQFP package.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGING/ORDERING INFORMATION⁽¹⁾

PACKAGED DEVICES	PACKAGE TYPE	TRANSPORT MEDIA, QUANTITY
THS7347IPHP	LITOED 40 Device DADIM	Tray, 250
THS7347IPHPR	HTQFP-48 PowerPAD™	Tape and Reel, 1000

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

ABSOLUTE MAXIMUM RATINGS(1)

Over operating free-air temperature range (unless otherwise noted).

			THS7347	UNIT
V _{SS}	Supply voltage, GND	to V _A or GND to V _{DD}	5.5	V
VI	Input voltage		–0.4 to V _A or V _{DD}	V
lo	Continuous output cu	rrent	±80	mA
	Continuous power dis	sipation	See Dissipatio	n Rating Table
T _J	Maximum junction ter	nperature, any condition (2)	+150	°C
TJ	Maximum junction ter	nperature, continuous operation, long term reliability (3)	+125	°C
T _{stg}	Storage temperature	range	-65 to +150	°C
	Lead temperature 1,6	mm (1/16 inch) from case for 10 seconds	300	°C
		НВМ	1500	V
	ESD ratings	CDM	1500	V
		MM	100	V

⁽¹⁾ Stresses above those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied Exposure to absolute maximum rated conditions for extended periods may degrade device reliability.

(2) The absolute maximum junction temperature under any condition is limited by the constraints of the silicon process.

DISSIPATION RATINGS

	θυς	θ _{JA}		ATING ^{(1) (2)} +125°C)	
PACKAGE	(°Č/W)	(°C/W)	T _A = +25°C	T _A = +85°C	
HTQFP-48 with PowerPAD (PHP)	1.2	35	2.85 W	1.14 W	

⁽¹⁾ This data was taken with a PowerPAD standard 3-inch by 3-inch, 4-layer printed circuit board (PCB) with internal ground plane connections to the PowerPAD.

⁽³⁾ The absolute maximum junction temperature for continuous operation is limited by the package constraints. Operation above this temperature may result in reduced reliability and/or lifetime of the device.

⁽²⁾ Power rating is determined with a junction temperature of +125°C. This temperature is the point where distortion starts to substantially increase and long-term reliability starts to be reduced. Thermal management of the final PCB should strive to keep the junction temperature at or below +125°C for best performance and reliability.

www.ti.com

RECOMMENDED OPERATING CONDITIONS

		MIN	NOM N	ΛAΝ	UNIT
V_{DD}	Digital supply voltage	2.7		5	V
V_A	Analog supply voltage. Must be equal to or greater than $V_{\mbox{\scriptsize DD}}$	V_{DD}		5	V
T_A	Ambient temperature	-40		+85	°C

ELECTRICAL CHARACTERISTICS, $V_A = V_{DD} = 3.3 \text{ V}$

 R_L = 150 Ω || 5 pF to GND for Monitor Output, 19 k Ω || 8 pF Load to GND for Buffer Output, SAG pin shorted to Monitor Output Pin, unless otherwise noted.

PARAME AC PERFORMANCE	TER				000:			
		TEST CONDITIONS	+25°C	+25°C	0°C to +70°C	–40°C to +85°C	UNIT	MIN/MAX/ TYP
Small-signal	Buffer output		500				MHz	Тур
1 1 1 1 1 1 (0 10)	Monitor output	$V_O = 0.2 V_{PP}$	450				MHz	Тур
. 15 ()	Buffer output		425				MHz	Тур
–1 dB flatness	Monitor output	$V_0 = 0.2 V_{PP}$	375				MHz	Тур
Large-signal	Buffer output	V _O = 1 V _{PP}	475				MHz	Тур
1 1 1 M (0 ID)	Monitor output	$V_O = 2 V_{PP}$	240				MHz	Тур
0	Buffer output	V _O = 1 V _{PP}	1050				V/µs	Тур
Slew rate	Monitor output	$V_O = 2 V_{PP}$	1050				V/µs	Тур
Group delay at	Buffer output		1.2				ns	Тур
400 1:11-	Monitor output		1.2				ns	Тур
5 ′′′	Buffer output	NETO (DA)	0.05/0.05				%	Тур
Differential gain	Monitor output	NTSC/PAL	0.1/0.1				%	Тур
	Buffer output		0.1/0.15				degrees	Тур
Differential phase	Monitor output	NTSC/PAL	0.15/0.2				degrees	Тур
Total harmonic	Buffer output	V _O = 1 V _{PP}	-58				dB	Тур
distantian £ 4 MIII	Monitor output	$V_O = 2 V_{PP}$	-57				dB	Тур
	Buffer output		63				dB	Тур
Signal-to-noise ratio	Monitor output	No weighting, up to 100 MHz	65				dB	Тур
Channel-to-channel	Buffer output	f = 100 MHz	-40				dB	Тур
onamic to chamic	Monitor output		-36				dB	Тур
	Buffer output	f = 100 MHz	64				dB	Тур
MUX isolation	Monitor output		66				dB	Тур
	Buffer output	f = 100 kHz; V _O = 1 V _{PP}	0				dB	Тур
Gain	Monitor output	f = 100 kHz; V _O = 2 V _{PP}	6	5.8/6.25	5.75/6.3	5.75/6.35	dB	Min/Max
	Buffer output	7 0 11	6				ns	Тур
Settling time	Monitor output	$V_{IN} = 1 V_{PP}$; 0.5% settling	6				ns	Тур
	Buffer output		0.3				Ω	Тур
Output impedance	Monitor output	f = 10 MHz	0.4				Ω	Тур
DC PERFORMANCE								- 71-
	Buffer output		15	±80	±85	±85	mV	Max
Output offset voltage	Monitor output	Bias = dc	20	±120	±125	±125	mV	Max
	Buffer output		20	1120	1120	20	μV/°C	Тур
Average offset	Monitor output	Bias = dc				20	μV/°C	Тур
	mornior output	Bias = dc + shift, V _{IN} = 0 V	255	175/355	165/365	160/370	mV	Min/Max
	Buffer output	Bias = ac	1.0	0.85/1.15	0.8/1.2	0.8/1.2	V	Min/Max
Bias output voltage		Bias = ac Bias = dc + shift, $V_{IN} = 0 \text{ V}$	235	145/350	135/360	130/365	mV	Min/Max
	Monitor output	Bias = ac Bias = ac	1.7	1.55/1.85	1.5/1.9	1.5/1.9	V	Min/Max
0 " 1	Ruffor output	Dias = ac	290	200/405	1.5/1.9	190/415	mV	Min/Max
- t	Buffer output Magitar output Bias = ac STC, clamp voltage							
voltage	Monitor output	, , ,	300	200/400	195/405	190/410	mV	Min/Max



ELECTRICAL CHARACTERISTICS, $V_A = V_{DD} = 3.3 \text{ V}$ (continued)

 R_L = 150 Ω || 5 pF to GND for Monitor Output, 19 k Ω || 8 pF Load to GND for Buffer Output, SAG pin shorted to Monitor Output Pin, unless otherwise noted.

			TYP		OVE	R TEMPERA	TURE	
PARAI	METER	TEST CONDITIONS	+25°C	+25°C	0°C to +70°C	–40°C to +85°C	UNIT	MIN/MAX/ TYP
DC PERFORMANC	E, continued						•	
Input bias current		Bias = dc; (–) implies I _B out of the pin	-1.3	-3.0	-3.5	-3.5	μA	Max
Average bias curren	t drift	Bias = dc				10	nA/°C	Тур
		Bias = ac STC, low bias	2.3	0.9/3.6	0.8/3.8	0.7/3.9	μA	Min/Max
Sync tip clamp bias	current	Bias = ac STC, mid bias	5.8	3.8/8.0	3.7/8.2	3.6/8.3	μA	Min/Max
		Bias = ac STC, high bias	8.1	5.7/10.8	5.6/11.0	5.5/11.1	μA	Min/Max
INPUT CHARACTE	RISTICS			1				
Input voltage range		Bias = dc	0 to 2				V	Тур
		Bias = ac bias mode	25				kΩ	Тур
Input resistance		Bias = dc, dc + shift, ac STC	3				ΜΩ	Тур
Input capacitance			1.5				pF	Тур
OUTPUT CHARAC	TERISTICS: MONIT	TOR OUTPUT						7.
		$R_L = 150 \Omega \text{ to } 1.65 \text{ V}$	3.15	2.9	2.8	2.8	V	Min
		$R_1 = 150 \Omega$ to GND	3.05	2.85	2.75	2.75	V	Min
High output voltage	swing	R ₁ = 75 Ω to 1.65 V	3.05				V	Тур
		$R_L = 75 \Omega$ to GND	2.9				V	Тур
Low output voltage swing		R _I = 150 Ω to 1.65 V	0.15	0.25	0.28	0.29	V	Max
		$R_L = 150 \Omega$ to GND	0.1	0.18	0.21	0.22	V	Max
		R ₁ = 75 Ω to 1.65 V	0.25				V	Тур
		$R_L = 75 \Omega \text{ to GND}$	0.08				V	Тур
	Sourcing	1,2 19 12 10 6112	80	50	47	45	mA	Min
Output current	Sinking	R_L = 10 Ω to 1.65 V	75	50	47	45	mA	Min
OUTPUT CHARACT		ER OUTPUT						
High output voltage								Ī
(Limited by input rar		Lood - 10 kO 9 pE to 1 65 V	2	1.8	1.75	1.75	V	Min
Low Output voltage (Limited by input rar	swing age and G = 0 dB)	Load = 19 kΩ ∥ 8 pF to 1.65 V	0.05	0.12	0.13	0.14	V	Max
Output Current	Sourcing	$R_L = 10 \Omega$ to GND	80	50	47	45	mA	Min
Odiput Current	Sinking	$R_L = 10 \Omega$ to 1.65 V	75	50	47	45	mA	Min
POWER SUPPLY:	ANALOG							
Maximum operating	voltage	V_A	3.3	5.5	5.5	5.5	V	Max
Minimum operating	voltage	V _A	3.3	2.7	2.7	2.7	V	Min
Maximum quiescent	current	V_A , dc + shift mode, V_{IN} = 100 mV	80	100	103	105	mA	Max
Minimum quiescent	current	V_A , dc + shift mode, V_{IN} = 100 mV	80	60	57	55	mA	Min
Power supply rejecti	on (+PSRR)	Buffer output	50				dB	Тур
POWER SUPPLY: I	DIGITAL							
Maximum operating	voltage	V_{DD}	3.3	5.5	5.5	5.5	V	Max
Minimum operating	voltage	V _{DD}	3.3	2.7	2.7	2.7	V	Min
Maximum quiescent current		V_{DD} , $V_{IN} = 0 V$	0.65	1.2	1.3	1.4	mA	Max
Minimum quiescent	current	V_{DD} , $V_{IN} = 0$ V	0.65	0.35	0.3	0.25	mA	Min
DISABLE CHARAC	TERISTICS: ALL C	CHANNELS DISABLED	*	•			•	*
Quiescent current		All channels disabled	0.1				μA	Тур
Turn-on time delay (t _{ON})	Time for I _S to reach 50% of final value	5				μs	Тур
Turn-on time delay (torr)	after I ² C control is initiated	2				μs	Тур



ELECTRICAL CHARACTERISTICS, $V_A = V_{DD} = 3.3 \text{ V}$ (continued)

 R_L = 150 Ω || 5 pF to GND for Monitor Output, 19 k Ω || 8 pF Load to GND for Buffer Output, SAG pin shorted to Monitor Output Pin, unless otherwise noted.

		TYP		OVER TEMPERATURE			
PARAMETER	TEST CONDITIONS	+25°C +25°C		0°C to +70°C	–40°C to +85°C	UNIT	MIN/MAX/ TYP
DIGITAL CHARACTERISTICS(1)			1				
High level input voltage	V _{IH}	2.3				V	Тур
Low level input voltage	V _{IL}	1.0				V	Тур
H/V SYNC CHARACTERISTICS: R _{Lo}	$_{\rm ad}$ = 1 k Ω To GND ⁽²⁾						
Schmitt trigger adjust pin voltage	Reference for Schmitt trigger	1.47	1.35/1.6	1.3/1.65	1.27/1.68	V	Min/Max
Schmitt trigger threshold range	Allowable range for Schmitt trigger adjust	0.9 to 2				V	Тур
Schmitt trigger VT+	Positive-going input voltage threshold relative to Schmitt trigger threshold					V	Тур
Schmitt trigger VT-	Negative-going input voltage threshold relative to Schmitt trigger threshold	-0.3				V	Тур
Schmitt trigger threshold pin input resistance	Input resistance into Control pin	10				kΩ	Тур
H/V Sync input impedance		10				МΩ	Тур
H/V Sync high output voltage	1 kΩ to GND	3.15	3.05	3.0	3.0	V	Min
H/V Sync low output voltage	1 kΩ to GND	0.01	0.05	0.1	0.1	V	Max
H/V Sync source current	10 Ω to GND	50	35	30	30	mA	Min
H/V Sync sink current	10 Ω to 3.3 V	35	25	23	21	mA	Min
H/V Delay	Delay from Input to output	6.5				ns	Тур
H/V to buffer output skew		5				ns	Тур

⁽¹⁾ Standard CMOS logic.
(2) Schmitt trigger threshold is defined by (VT+ - VT-)/2.



ELECTRICAL CHARACTERISTICS, $V_A = V_{DD} = 5 \text{ V}$

 R_L = 150 Ω || 5pF to GND for Monitor Output, 19k Ω || 8pF Load to GND for Buffer Output, SAG pin shorted to Monitor Output Pin, unless otherwise noted.

			TYP	TYP OVER TEMP				
PARAM	ETER	TEST CONDITIONS	+25°C	+25°C	0°C to +70°C	–40°C to +85°C	UNIT	MIN/MAX/ TYP
AC PERFORMANCE								
Small-signal	Buffer output		550				MHz	Тур
bandwidth (–3 dB)	Monitor output	$V_O = 0.2 V_{PP}$	500				MHz	Тур
	Buffer output		450				MHz	Тур
–1 dB flatness	Monitor output	$V_O = 0.2 V_{PP}$	400				MHz	Тур
Large-signal	Buffer output	$V_O = 1 V_{PP}$	525				MHz	Тур
bandwidth (–3 dB)	Monitor output	$V_O = 2 V_{PP}$	325				MHz	Тур
	Buffer output	V _O = 1 V _{PP}	1200				V/µs	Тур
Slew rate	Monitor output	$V_O = 2 V_{PP}$	1350				V/µs	Тур
Group delay at	Buffer output		1.15				ns	Тур
100 kHz	Monitor output		1.15				ns	Тур
	Buffer output		0.05/0.05				%	Тур
Differential gain	Monitor output	NTSC/PAL	0.1/0.1				%	Тур
	Buffer output		0.05/0.05				degrees	Тур
Differential phase	Monitor output	NTSC/PAL	0.05/0.05				degrees	Тур
Total harmonic	Buffer output	V _O = 1 V _{PP}	-71				dB	Тур
distortion f = 1 MHz	Monitor output	$V_O = 2 V_{PP}$	-67				dB	Тур
	Buffer output		63				dB	Тур
Signal-to-noise ratio	Monitor output	No weighting, up to 100 MHz	65				dB	Тур
Channel-to-channel	Buffer output		-40				dB	Тур
crosstalk	Monitor output	f = 100 MHz	-36				dB	Тур
MUX Isolation	Buffer output		64				dB	Тур
	Monitor output	f = 100 MHz	66				dB	Тур
0.1	Buffer output	f = 100 kHz; V _O = 1 V _{PP}	0				dB	Тур
Gain	Monitor output	f = 100 kHz; V _O = 2 V _{PP}	6	5.8/6.25	5.75/6.3	5.75/6.35	dB	Min/Max
0	Buffer output	V 4 V 2 TO 4 VIII	6				ns	Тур
Settling time	Monitor output	$V_{IN} = 1 V_{PP}$; 0.5% settling	6				ns	Тур
0	Buffer output	(40.11)	0.3				Ω	Тур
Output impedance	Monitor output	f = 10 MHz	0.4				Ω	Тур
DC PERFORMANCE				•			•	
0	Buffer output	D: I	15	±80	±85	±85	mV	Max
Output offset voltage	Monitor output	Bias = dc	20	±120	±125	±125	mV	Max
Average offset	Buffer output	D: I				20	μV/°C	Тур
voltage drift	Monitor output	Bias = dc				20	μV/°C	Тур
	5 "	Bias = dc + shift, V _{IN} = 0 V	265	185/370	175/380	170/385	mV	Min/Max
D'	Buffer output	Bias = ac	1.5	1.3/1.65	1.25/1.7	1.25/1.7	V	Min/Max
Bias output voltage		Bias = dc + shift, V _{IN} = 0 V	235	145/345	135/355	130/360	mV	Min/Max
	Monitor output	Bias = ac	2.65	2.5/2.8	2.45/2.85	2.45/2.85	V	Min/Max
Sync tip clamp	Buffer output	Biography #	295	205/410	200/415	195/420	mV	Min/Max
voltage	Monitor output	Bias = ac STC, clamp voltage	300	200/400	195/405	190/410	mV	Min/Max
Input bias current	•	Bias = dc; (–) implies I _B out of the pin	-1.4	-3.0	-3.5	-3.5	μΑ	Max
Average bias current	drift	Bias = dc				10	nA/°C	Тур
		Bias = ac STC, low bias	2.4	0.9/3.9	0.8/4.0	0.7/4.1	μA	Min/Max
Sync tip clamp bias c	urrent	Bias = ac STC, mid bias	6.2	3.9/8.4	3.8/8.6	3.7/8.7	μA	Min/Max
		Bias = ac STC, high bias	8.6	6/11.2	5.8/11.4	5.7/11.5	μΑ	Min/Max



ELECTRICAL CHARACTERISTICS, $V_A = V_{DD} = 5 V$ (continued)

 R_L = 150 Ω || 5pF to GND for Monitor Output, 19k Ω || 8pF Load to GND for Buffer Output, SAG pin shorted to Monitor Output Pin, unless otherwise noted.

			TYP		OVER TEMPERATURE			
PARA	METER	TEST CONDITIONS	+25°C +25°C		0°C to +70°C	-40°C to +85°C	UNIT	MIN/MAX/ TYP
INPUT CHARACTE	RISTICS							
Input voltage range		Bias = dc	0 to 3.4				V	Тур
Innut registance		Bias = ac bias mode	25				kΩ	Тур
Input resistance		Bias = dc, dc + shift, ac STC	3				МΩ	Тур
Input capacitance			1.5				pF	Тур
OUTPUT CHARAC	TERISTICS: MONIT	OR OUTPUT						
		R_L = 150 Ω to 2.5 V	4.8	4.65	4.6	4.6	V	Min
High output voltage swing		$R_L = 150 \Omega$ to GND	4.7	4.55	4.5	4.5	V	Min
riigii output voitage	Swirig	$R_L = 75 \Omega$ to 2.5 V	4.7				V	Тур
		$R_L = 75 \Omega$ to GND	4.6				V	Тур
		$R_L = 150 \Omega$ to 2.5 V	0.2	0.25	0.28	0.30	V	Max
Law autout valtage	avvia a	$R_L = 150 \Omega$ to GND	0.1	0.19	0.23	0.24	V	Max
Low output voltage sv	swing	$R_L = 75 \Omega$ to 2.5 V	0.24				V	Тур
		$R_L = 75 \Omega$ to GND	0.085				V	Тур
0.44	Sourcing	D 40.04-05.V	110	85	80	75	mA	Min
Output current	Sinking	$R_L = 10 \Omega \text{ to } 2.5 \text{ V}$	110	85	80	75	mA	Min
OUTPUT CHARAC	TERISTICS: BUFFE	R OUTPUT	"					
High output voltage swing (Limited by input range and G = 0 dB)		Load = 19 kΩ 8 pF to 2.5 V	3.4	3.1	3.0	3.0	V	Min
Low output voltage swing (Limited by input range and G = 0 dB)		Load = 13 K12 0 pr to 2.5 v	0.05	0.12	0.13	0.14	V	Max
Output ourrent	Sourcing	$R_L = 10 \Omega$ to GND	110	85	80	75	mA	Min
Output current	Sinking	$R_L = 10 \Omega$ to 2.5 V	110	85	80	75	mA	Min
POWER SUPPLY:	ANALOG							
Maximum operating	voltage	V _A	5.0	5.5	5.5	5.5	V	Max
Minimum operating	voltage	V _A	5.0	2.7	2.7	2.7	V	Min
Maximum quiescent	current	V_A , dc + shift mode, V_{IN} = 100 mV	90	112	115	117	mA	Max
Minimum quiescent	current	V_A , dc + shift mode, V_{IN} = 100 mV	90	68	65	63	mA	Min
Power supply reject	ion (+PSRR)	Buffer Output	46				dB	Тур
POWER SUPPLY:	DIGITAL							
Maximum operating	voltage	V_{DD}	5.0	5.5	5.5	5.5	V	Max
Minimum operating	voltage	V_{DD}	5.0	2.7	2.7	2.7	V	Min
Maximum quiescent	current	V_{DD} , $V_{IN} = 0 V$	1	2	3	3	mA	Max
Minimum quiescent	current	V_{DD} , $V_{IN} = 0 V$	1	0.5	0.4	0.4	mA	Min
DIGITAL CHARAC	TERISTICS ⁽¹⁾							
High level input volta	age	V _{IH}	3.5				V	Тур
Low level input volta	age	V _{IL}	1.5				V	Тур
DISABLE CHARAC	TERISTICS: ALL C	HANNELS DISABLED		-	.			
Quiescent current		All channels disabled	1				μA	Тур
Turn-on time delay	(t _{ON})	Time for I _S to reach 50% of final value	5				μs	Тур
Turn-on time delay	(t _{OFF})	after I ² C control is initiated	2				μs	Тур

⁽¹⁾ Standard CMOS logic.



ELECTRICAL CHARACTERISTICS, $V_A = V_{DD} = 5 \text{ V}$ (continued)

 R_L = 150 Ω || 5pF to GND for Monitor Output, 19k Ω || 8pF Load to GND for Buffer Output, SAG pin shorted to Monitor Output Pin, unless otherwise noted.

		TYP		OVER TEMPERAT 0°C to		TURE	
PARAMETER	TEST CONDITIONS	+25°C	+25°C			UNIT	MIN/MAX/ TYP
H/V SYNC CHARACTERISTICS: RLo	$_{\rm ad}$ = 1 k Ω To GND ⁽²⁾						
Schmitt trigger adjust pin voltage	Reference for Schmitt trigger	1.54	1.43/1.65	1.38/1.7	1.35/1.73	V	Min/Max
Schmitt trigger threshold range	Allowable range for Schmitt trigger adjust	0.9 to 2				V	Тур
Schmitt trigger VT+	Positive-going input voltage threshold relative to Schmitt trigger threshold	0.25				V	Тур
Schmitt trigger VT-	Negative-going input voltage threshold relative to Schmitt trigger threshold	-0.3				V	Тур
Schmitt trigger threshold pin input resistance	Input resistance into Control pin	10				kΩ	Тур
H/V Sync input impedance		10				МΩ	Тур
H/V Sync high output voltage	1 kΩ to GND	4.8	4.7	4.6	4.6	V	Min
H/V Sync low output voltage	1 kΩ to GND	0.01	0.05	0.1	0.1	V	Max
H/V Sync source current	10 Ω to GND	90	60	55	55	mA	Min
H/V Sync sink current	10 Ω to 5 V	50	30	27	25	mA	Min
H/V Delay	Delay from input to output	6.5				ns	Тур
H/V to buffer output skew		5				ns	Тур

⁽²⁾ Schmitt trigger threshold is defined by (VT+ - VT-)/2.



TIMING REQUIREMENTS FOR I²C INTERFACE⁽¹⁾⁽²⁾

At $V_{DD} = 2.7 \text{ V to 5 V}$.

		STANDARD	MODE	FAST N	1	
	PARAMETER	MIN	MAX	MIN	MAX	UNIT
f _{SCL}	Clock frequency, SCL	0	100	0	400	kHz
t _{w(H)}	Pulse duration, SCL high	4		0.6		μs
t _{w(L)}	Pulse duration, SCL low	4.7		1.3		μs
t _r	Rise time, SCL and SDA		1000		300	ns
t _f	Fall time, SCL and SDA		300		300	ns
t _{su(1)}	Setup time, SDA to SCL	250		100		ns
t _{h(1)}	Hold time, SCL to SDA	0		0		ns
t _(buf)	Bus free time between stop and start conditions	4.7		1.3		μs
t _{su(2)}	Setup time, SCL to start condition	4.7		0.6		μs
t _{h(2)}	Hold time, start condition to SCL	4		0.6		μs
t _{su(3)}	Setup time, SCL to stop condition	4		0.6		μs
C _b	Capacitive load for each bus line		400		400	pF

- The THS7347 I^2C address = 01011(A1)(A0)($R\overline{NV}$). See the *Applications Information* section for more information. The THS7347 was designed to comply with version 2.1 of the I^2C specification.

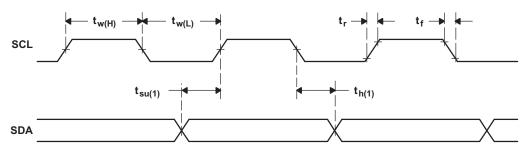


Figure 1. SCL and SDA Timing

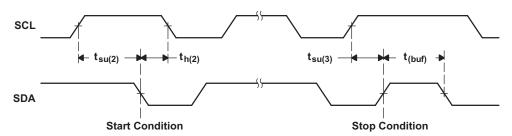
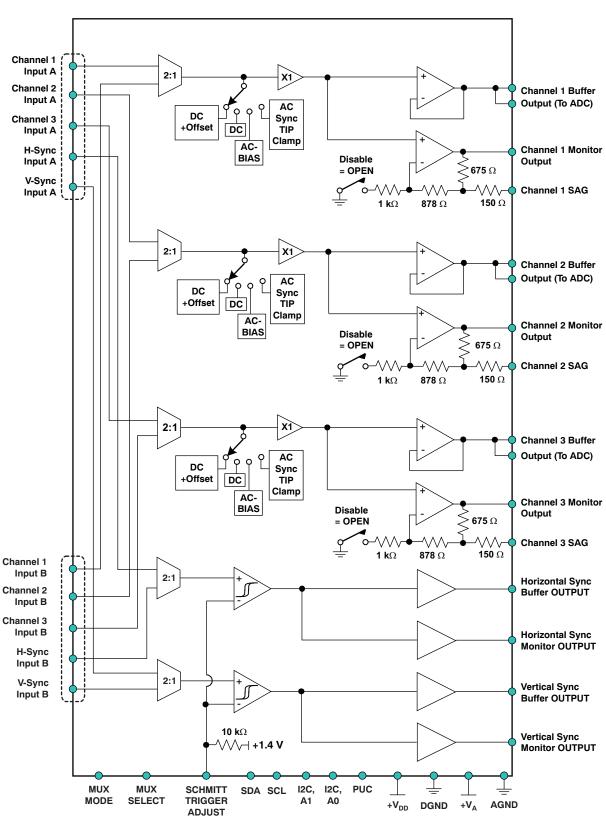


Figure 2. Start and Stop Conditions



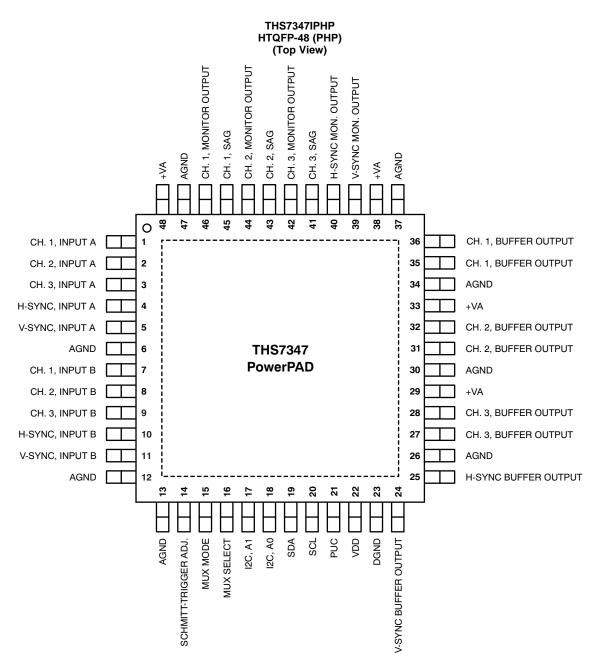
FUNCTIONAL BLOCK DIAGRAM



NOTE: The I²C address of the THS7347 is $01011(A1)(A0)(R/\overline{W})$.



PIN CONFIGURATION



TERMINAL FUNCTIONS

	TERMINAL FOROTIONS								
TERMINA	TERMINAL		DESCRIPTION						
NAME	NO.	1/0	DESCRIPTION						
CH. 1, INPUT A	1	I	Video Input Channel 1, Input A						
CH. 2, INPUT A	2	1	Video Input Channel 2, Input A						
CH. 3, INPUT A	3	ı	Video Input Channel 3, Input A						
H-SYNC, INPUT A	4	I	Horizontal Sync, Input A						
V-SYNC, INPUT A	5	I	Vertical Sync, Input A						
CH. 1, INPUT B	7	ı	Video Input Channel 1, Input B						
CH. 2, INPUT B	8	ı	Video Input Channel 2, Input B						
CH. 3, INPUT B	9	I	Video Input Channel 3, Input B						



TERMINAL FUNCTIONS (continued)

TERMINAL			TERMINAL FONCTIONS (Continued)						
NAME	NO.	I/O	DESCRIPTION						
H-SYNC, INPUT B	10		Horizontal Sync, Input B						
V-SYNC, INPUT B	11	1	Vertical Sync, Input B						
I ² C, A1	17	I	I ² C Slave Address Control Bit A1. Connect to V _{DD} for a logic 1 preset value or GND for a logic 0 preset value.						
I ² C, A0	18	I	I ² C Slave Address Control Bit A0. Connect to V _{DD} for a logic 1 preset value or GND for a logic 0 preset value.						
SDA	19	I/O	Serial data line of the I^2C bus. Pull-up resistor should have a minimum value = 2 k Ω and a maximum value = 19 k Ω . Pull up to V_{DD} .						
SCL	20	I	I^2C bus clock line. Pull-up resistor should have a minimum value = 2 kΩ and a maximum value = 19 -kΩ. Pull up to V_{DD} .						
PUC	21	I	Power-Up Condition. Connect to GND for all channels disabled upon power-up. Connect to V _{DD} (logic high) to set buffer outputs to OFF and monitor outputs ON with ac-bias configuration on Channels 1 to 3 and both H-Sync/V-Sync enabled.						
MUX MODE	15	I	Sets the MUX configuration control. Connect to logic low for MUX Select (pin 16) control of the MUX. Connect to logic high for I ² C control of the MUX.						
MUX SELECT	16	I	Controls the MUX selection when MUX MODE (pin 15) is set to logic low. Connect to logic low for MUX selector set to Input A. Connect to logic high for MUX selector set to Input B.						
CH. 1, BUFFER OUTPUT	35, 36	0	Output Channel 1 from either CH. 1, INPUT A or CH. 1, INPUT B. Connect to ADC/Scalar/Decoder. Both pins should be connected together on the PCB.						
CH. 2, BUFFER OUTPUT	31, 32	0	Output Channel 2 from either CH. 2, INPUT A or CH. 2, INPUT B. Connect to ADC/Scalar/Decoder. Both pins should be connected together on the PCB.						
CH. 3, BUFFER OUTPUT	27, 28	0	Output Channel 3 from either CH. 3, INPUT A or CH. 3, INPUT B. Connect to ADC/Scalar/Decoder. Both pins should be connected together on the PCB.						
H-SYNC BUFFER OUTPUT	25	0	Horizontal Sync Buffer Output. Connect to ADC/Scalar H-sync input.						
V-SYNC BUFFER OUTPUT	24	0	Vertical Sync Buffer Output. Connect to ADC/Scalar V-sync input.						
CH. 1, SAG	45	0	Video Monitor Pass-Through Output Channel 1 SAG Correction pin. If SAG is not used, connect Directly to CH. 1, OUTPUT pin 46.						
CH. 1, MONITOR OUTPUT	46	0	Video Monitor Pass-Through Output Channel 1 from either CH. 1, INPUT A or CH. 1, INPUT B.						
CH. 2, SAG	43	0	Video Monitor Pass-Through Output Channel 2 SAG Correction pin. If SAG is not used, connect Directly to CH. 2, OUTPUT pin 44.						
CH. 2, MONITOR OUTPUT	44	0	Video Monitor Pass-Through Output Channel 2 from either CH. 2, INPUT A or CH. 2, INPUT B.						
CH. 3, SAG	41	0	Video Monitor Pass-Through Output Channel 3 SAG Correction pin. If SAG is not used, connect Directly to CH. 3, OUTPUT pin 42.						
CH. 3, MONITOR OUTPUT	42	0	Video Monitor Pass-Through Output Channel 3 from either CH. 3, INPUT A or CH. 3, INPUT B.						
H-SYNC MONITOR OUTPUT	40	0	Horizontal Sync Monitor Pass-Through Output.						
V-SYNC MONITOR OUTPUT	39	0	Vertical Sync Monitor Pass-Through Output.						
AGND	6, 12, 13, 26, 30, 34, 37, 47	I	Ground Reference pin for analog signals. Internally, these pins connect to DGND, although it is recommended to have the AGND and DGND connected to the proper signals for best results.						
+V _A	29, 33, 38, 48	I	Analog Positive Power Supply Input pins. Connect to 2.7 V to 5 V. Must be equal to or greater than VDD.						
V_{DD}	22	I	Digital Positive Supply pin for I ² C circuitry and H-Sync/V-Sync outputs. Connect to 2.7 V to 5 V.						
DGND	23	I	Digital GND pin for HV circuitry and I ² C circuitry.						
Schmitt Trigger Adjust	14	I	Defaults to 1.45 V (TTL compatible). Connect to external voltage reference to adjust H-Sync/V-Sync input thresholds from 0.9 V to 2 V range.						



APPLICATIONS INFORMATION

The THS7347 is targeted for RGB+HV video buffer applications. Although it can be used for numerous other applications, the needs and requirements of the video signal were the most important design parameters of the THS7347. Built on the revolutionary complementary silicon-germanium (SiGe) BiCom3 process, the THS7347 incorporates many features not typically found in integrated video parts while consuming very low power. Each channel configuration is completely independent of the other channels. This architecture allows for any configuration for each channel to be dictated by the end user, rather than the part dictating what the configuration must be—resulting in a highly flexible system.

The THS7347 has the following features:

- I²C interface for easy interfacing to the system.
- Single-supply 2.7-V to 5-V operation with low quiescent current of 80 mA at 3.3 V.
- · 2:1 input mux.
- Input configuration accepts dc, dc + shift, ac bias, or ac sync-tip clamp selection.
- 500-MHz unity-gain buffer amplifier to drive ADC/Scalar/Decoder.
- Monitor Pass-Through path has an internal fixed gain of 2 V/V (+6 dB) amplifier that can drive two video lines per channel with dc coupling, traditional ac coupling, or SAG-corrected ac coupling.
- While disabled, the Monitor Pass-Through path has a very high output impedance (> 500 kΩ || 8 pF)
- Power-Up Control (PUC) allows the THS7347 to be fully disabled or have the Monitor Pass-Through function (with ac-bias mode on all channels) enabled upon initial device power-up.
- Mux is controlled by either I²C or a general-purpose input/output (GPIO) pin, based on the MUX Mode pin logic.
- H-Sync and V-Sync paths have an externally-adjustable Schmitt trigger threshold
- Disable mode reduces quiescent current to as low as 0.1-µA.

OPERATING VOLTAGE

The THS7347 is designed to operate from 2.7 V to 5 V over a -40°C to +85°C temperature range. The impact on performance over the entire temperature range is negligible because of the implementation of thin film resistors and high-quality, low temperature coefficient capacitors.

A 0.1- μ F to 0.01- μ F capacitor should be placed as close as possible to the power-supply pins. Failure to do so may result in the THS7347 outputs ringing or oscillating. Additionally, a large capacitor, such as 100 μ F, should be placed on the power-supply line to minimize issues with 50-Hz/60-Hz line frequencies.

INPUT VOLTAGE

The THS7347 input range allows for an input signal range from ground to approximately ($V_S+-1.6$ V). However, because of the internal fixed gain of 2 V/V (+6 dB), the output is generally the limiting factor for the allowable linear input range. For example, with a 5-V supply, the linear input range is from GND to 3.4 V. As a result of the gain, the linear output range limits the allowable linear input range from GND to 2.5 V at most.



INPUT OVERVOLTAGE PROTECTION

The THS7347 is built using a very high-speed complementary bipolar and CMOS process. The internal junction breakdown voltages are relatively low for these very small geometry devices. These breakdowns are reflected in the Absolute Maximum Ratings table. All input and output device pins are protected with internal ESD protection diodes to the power supplies, as shown in Figure 3.

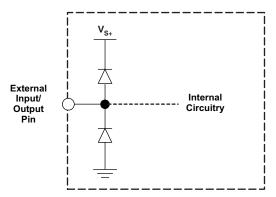


Figure 3. Internal ESD Protection

These diodes provide moderate protection to input overdrive voltages above and below the supplies. The protection diodes can typically support 30 mA of continuous current when overdriven.

TYPICAL CONFIGURATION

A typical application circuit usng the THS7347 as an ac-coupled input video buffer is shown in Figure 4. It shows the THS7347 driving a video ADC (such as the TVP7000) with 0-dB gain and also driving an output line with 6-dB gain. The Horizontal and Vertical Sync signals are also driven to the ADC and the Monitor Output separately. Although the computer resolution R'G'B'HV signals are shown, these channels can easily be the high-definition video (HD), enhanced-definition (ED), or standard-definition (SD) Y'P'_BP'_R (sometimes labeled Y'U'V' or incorrectly labeled Y'C'_BC'_R) channels. These channels could also be S-Video Y'/C' channels and the composite video baseband signal (CVBS). Note that the R'G'B' channels could be professional/broadcast G'B'R' signals or other R'G'B' variations based on the placement of the sync signals that are commonly called R'G'sB' (sync on Green) or R'sG'sB's (sync on all signals).

The second set of inputs (B-Channels) shown are connected to another set of inputs. Again, these inputs can be either HD, ED, SD, or R'G'B'/G'B'R' video signals. The THS7347 flexibility allows for virtually any input signal to be driven into the THS7347 regardless of the other set of inputs. Simple control of the I²C configures the THS7347 for any conceivable combination. For example, the THS7347 can be configured to have Channel 1 Input connected to input A while Channel 2 and Channel 3 are connected to input B. See the multiple application notes sections explaining the I²C interface later in this document for details on configuring these options.

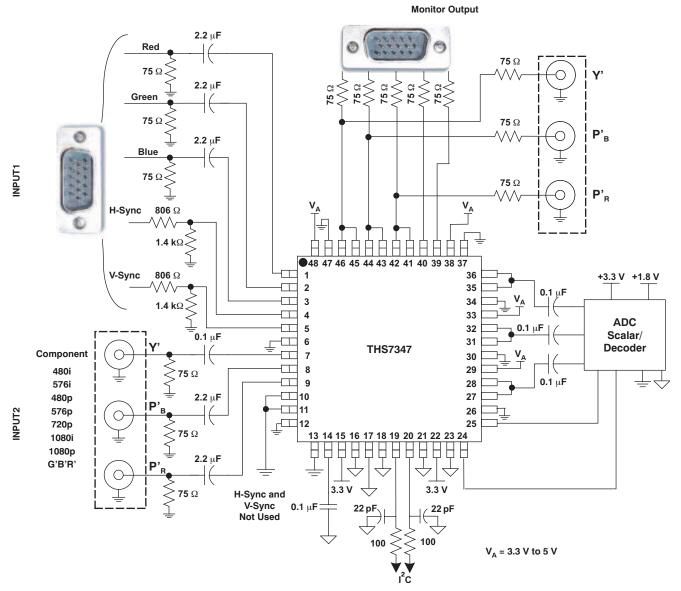
Note that the Y' term is used for the luma channels throughout this document, rather than the more common luminance (Y) term. The reason for this usage is to account for the true definition of luminance as stipulated by the CIE (International Commission on Illumination). Video departs from true luminance because a nonlinear term, gamma, is added to the true RGB signals to form R'G'B' signals. These R'G'B' signals are then utilized to mathematically create luma (Y'). Therefore, true luminance (Y) is not maintained, and thus the difference in terminology arises.

This rationale is also utilized for the chroma (C') term. Chroma is derived from the nonlinear R'G'B' terms and therefore it is also nonlinear. True chominance (C) is derived from linear RGB, and thus the difference between chroma (C') and chrominance (C) exists. The color difference signals ($P'_B/P'_R/U'/V'$) are also referenced this way to denote the nonlinear (gamma-corrected) signals.

R'G'B' (commonly labeled RGB) is also called G'B'R' (again commonly labeled as GBR) in professional video systems. The SMPTE component standard stipulates that the luma information is placed on the first channel, the blue color difference is placed on the second channel, and the red color difference signal is placed on the third channel. This approach is consistent with the Y'P'_BP'_R nomenclature. Because the luma channel (Y') carries the sync information and the green channel (G') also carries the sync information, it makes logical sense that G' be



placed first in the system. Since the blue color difference channel (P'_B) is next and the red color difference channel (P'_R) is last, then it also makes logical sense to place the B' signal on the second channel and the R' signal on the third channel, respectively. Thus, hardware compatibility is better achieved when using G'B'R' rather than R'G'B'. Note that for many G'B'R' systems, sync is embedded on all three channels; this configuration may not always be the case for all systems.



- (1) Inputs and/or outputs can be ac- or dc-coupled if desired.
- (2) H-Sync and V-Sync input resistance as shown above = $2.2 \text{ k}\Omega$, but may be changed to any desired resistance.
- (3) If the Monitor or Buffer PCB trace is > 25 mm, it is recommended to place at least a 10-Ω resistor in series with each signal to reduce PCB parasitic issues

Figure 4. Typical R'G'B'HV and Y'P'BP'R AC-Coupled Inputs and DC-Coupled Output Configuration



I²C INTERFACE NOTES

The I²C interface is used to access the internal registers of the THS7347. I²C is a two-wire serial interface developed by Philips Semiconductor (see the I²C Bus Specification, Version 2.1, January 2000). The THS7347 was designed in compliance with version 2.1 specifications. The bus consists of a data line (SDA) and a clock line (SCL) with pull-up structures. When the bus is idle, both SDA and SCL lines are pulled high. All the I²C-compatible devices connect to the I²C bus through open-drain I/O pins, SDA and SCL. A *master* device, usually a microcontroller or a digital signal processor, controls the bus. The master is responsible for generating the SCL signal and device addresses. The master also generates specific conditions that indicate the START and STOP of data transfer. A *slave* device receives and/or transmits data on the bus under control of the master device. The THS7347 works as a slave and supports the standard mode transfer (100 kbps) and fast mode transfer (400 kbps) as defined in the I²C Bus Specification. The THS7347 has been tested to be fully functional with the high-speed mode (3.4 Mbps) but it is not specified at this time.

Figure 5 shows the basic I²C start and stop access cycles.

The basic access cycle consists of the following:

- · A start condition
- · A slave address cycle
- · Any number of data cycles
- A stop condition

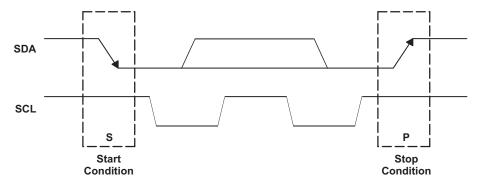


Figure 5. I²C Start and Stop Conditions

GENERAL I²C PROTOCOL

- The *master* initiates data transfer by generating a *start condition*. The *start condition* exists when a high-to-low transition occurs on the SDA line while SCL is high, as shown in Figure 5. All I²C-compatible devices should recognize a *start condition*.
- The master then generates the SCL pulses and transmits the 7-bit address and the read/write direction bit R/W on the SDA line. During all transmissions, the master ensures that data is valid. A valid data condition requires the SDA line to be stable during the entire high period of the clock pulse (see Figure 6). All devices recognize the address sent by the master and compare it to the respective internal fixed addresses. Only the slave device with a matching address generates an acknowledge (see Figure 7) by pulling the SDA line low during the entire high period of the ninth SCL cycle. On detecting this acknowledge, the master knows that a communication link with a slave has been established.

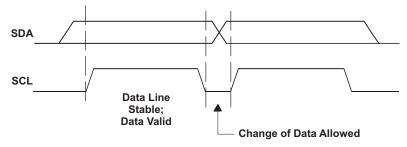


Figure 6. I²C Bit Transfer



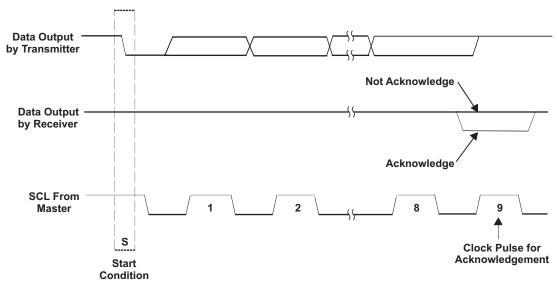


Figure 7. I²C Acknowledge

• The master generates further SCL cycles to either *transmit* data to the slave (R/W bit 1) or *receive* data from the slave (R/W bit 0). In either case, the *receiver* must acknowledge the data sent by the *transmitter*. So, an acknowledge signal can either be generated by the master or by the slave, depending on which one is the receiver. The 9-bit valid data sequences consisting of 8-bit data and 1-bit acknowledge can continue as long as necessary (see Figure 8).

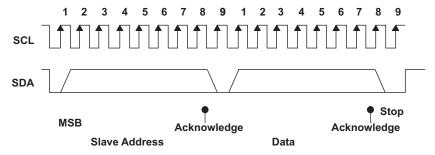
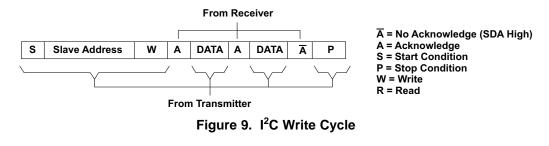


Figure 8. I²C Address and Data Cycles

• To signal the end of the data transfer, the master generates a *stop condition* by pulling the SDA line from low to high while the SCL line is high (see Figure 5). This transaction releases the bus and stops the communication link with the addressed slave. All I²C-compatible devices must recognize the *stop condition*. Upon the receipt of a stop condition, all devices know that the bus is released, and they wait for a *start condition* followed by a matching address.



During a write cycle, the transmitting device must not drive the SDA signal line during the acknowledge cycle, so that the receiving device may drive the SDA signal low. After each byte transfer following the address byte, the receiving device pulls the SDA line low for one SCL clock cycle. A stop condition is initiated by the transmitting device after the last byte is transferred. Figure 9 and Figure 10 show an example of a write cycle. Note that the THS7347 does not allow multiple write transfers to occur. See the example, **Writing to the THS7347**, in WRITE AND READ EXAMPLES for more information.



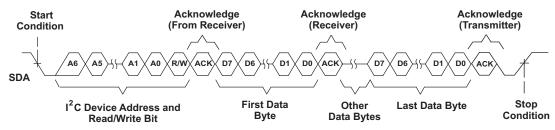


Figure 10. Multiple Byte Write Transfer

During a read cycle, the slave receiver acknowledges the initial address byte if it decodes the address as its address. Following this initial acknowledge by the slave, the master device becomes a receiver and acknowledges data bytes sent by the slave. When the master has received all of the requested data bytes from the slave, the not acknowledge (A) condition is initiated by the master by keeping the SDA signal high just before it asserts the stop (P) condition. This sequence terminates a read cycle, as shown in Figure 11 and Figure 12. Note that the THS7347 does not allow multiple read transfers to occur. See the example, **Reading from the THS7347**, in WRITE AND READ EXAMPLES for more information.

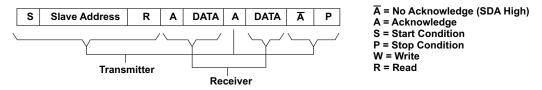


Figure 11. I²C Read Cycle

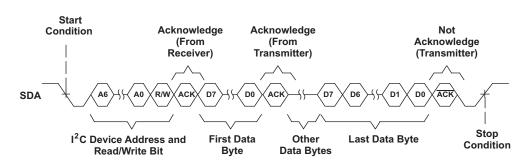


Figure 12. Multiple Byte Read Transfer



Slave Address

Both the SDA and the SCL must be connected to a positive supply voltage via a pull-up resistor. These resistors should range from 2 k Ω to 19 k Ω in order to comply with the I²C specification. When the bus is free, both lines are high. The address byte is the first byte received following the START condition from the master device. The first five bits (MSBs) of the address are factory-preset to 01011. The next two bits of the THS7347 address are controlled by the logic levels appearing on the I²C, A1 and I²C, A0 pins. The I²C, A1 and I²C, A0 address inputs can be connected to V_{DD} for logic 1, GND for logic 0, or actively driven by TTL/CMOS logic levels. The device address is set by the state of these pins and is not latched. Thus, a dynamic address control system could be used to incorporate several devices on the same system. Up to four THS7347 devices can be connected to the same I²C bus without requiring additional *glue* logic. Table 1 lists the possible addresses for the THS7347.

READ/WRITE SELECTABLE WITH **FIXED ADDRESS ADDRESS PINS** BIT Bit 0 (R/W) Bit 7 (MSB) Bit 5 Bit 3 Bit 2 (A1) Bit 1 (A0) Bit 6 Bit 4

Table 1. THS7347 Slave Addresses

Channel Selection Register Description (Subaddress) and Power-Up Condition (PUC) Pin

The THS7347 operates using only a single-byte transfer protocol similar to that illustrated in Figure 9 and Figure 11. The internal subaddress registers and the functionality of each are given in Table 2. When writing to the device, it is required to send one byte of data to the corresponding internal subaddress. If control of all three channels is desired, then the master must cycle through all the subaddresses (channels) one at a time; see the example, **Writing to the THS7347** (in WRITE AND READ EXAMPLES) for the proper procedure of writing to the THS7347.

During a read cycle, the THS7347 sends the data in its selected subaddress (or channel) in a single transfer to the master device requesting the information. See the **Reading from the THS7347** example (in WRITE AND READ EXAMPLES) for the proper procedure on reading from the THS7347.

On power-up, the THS7347 registers are dictated by the Power-Up Control (PUC) pin. If the PUC pin is tied to GND, the THS7347 powers up in a fully disabled state. If the PUC pin is tied to V_{DD} , upon power-up the THS7347 is configured in the following state: ADC buffers disabled, monitor pass-through enabled, and ac-bias on, for all three input channels. It remains in the state dictated by the PUC until a valid write sequence is completed.

	5
REGISTER NAME	BIT ADDRESS (b ₇ b ₆ b ₅ b ₀)
Channel 1	0000 0001
Channel 2	0000 0010
Channel 3	0000 0011
Channel H Sync, Channel V Sync, and Disable Controls	0000 0100

Table 2. THS7347 Channel Selection Register Bit Assignments



Channel Register Bit Descriptions

Each bit of the subaddress (channel selection) control register as described in the previous section allows the user to individually control the THS7347 functionality. This process allows the user to control the functionality of each channel independently with regard to the other channels. The bit description for Channel 1 through Channel 3 is shown in Table 3, while the H/V sync channels and the analog channel states are described in Table 4.

Table 3. THS7347 Channel Register (Channel 1 through Channel 3) Bit Decoder Table. Use with Register Bit Codes (0000 0001), (0000 0010), and (0000 0011)

BIT	FUNCTION	BIT VALUE(S)	RESULT
(MSB)	Sync-Tip Clamp Filter	0	500-kHz filter on the STC circuit
7	Sync-rip Clamp Filler	1	5-MHz filter on the STC circuit
		0000	MUX Input A
		0001	MUX Input A
		0010	MUX Input A
		0011	MUX Input A
		0100	MUX Input A
		0101	MUX Input B
		0110	MUX Input B
6.5.4.2	MILLY Coloation	0111	MUX Input B
6, 5, 4, 3	MUX Selection	1000	MUX Input B
	6, 5, 4, 3 MUX Selection	1001	MUX Input B
		1010	Reserved; do not care
		1011	Reserved; do not care
		1100	Reserved; do not care
		1101	Reserved; do not care
		1110	Reserved; do not care
		1111	Reserved; do not care
		0 0 0	Disables both monitor and buffer paths of the respective channel/register
		0 0 1	Channel Mute
	lowest Monto	010	Input Mode = dc
2, 1, 0	Input Mode +	0 1 1	Input Mode = dc + Shift
(LSB)	Operation	100	Input Mode = ac-bias
		1 0 1	Input Mode = ac-STC with low bias
		110	Input Mode = ac-STC with mid bias
		111	Input Mode = ac-STC with high bias

Bit 7 (MSB): Controls the sync-tip clamp filter. Useful only when AC-STC input mode is selected. **Bits 6, 5, 4, 3:** Selects the Input MUX channel.

Bits 2, 1, and 0 (LSB): Configures the channel mode and operation. See Table 4, Bits 6 and 5, for more information with respect to the enable/disable state.



Table 4. THS7347 Channel Register (H/V Sync Channel + Analog Channels State) Bit Decoder Table. Use in Conjunction With Register Bit Code (0000 0100)

BIT	FUNCTION	BIT VALUE(S)	RESULT
(MSB) 7	Reserved; Do not care	Х	Reserved; do not care
	Monitor Pass-Through Path Disable 6 Mode		Disables all monitor channels regardless of bits 2:0 of Register 1 through Register 3
б	(Use in Conjunction with Table 3)	1	Enables monitor channels functions dictated by each programmed register code
F	Buffer Path Disable Mode		Disables all buffer channels regardless of bits 2:0 of Register 1 through Register 3
5	(Use in Conjunction with Table 3)	1	Enables buffer channel functions dictated by each programmed register code
		0 0	MUX Input A
4.2	Vartical Cons Channel MLIV Calaction	0 1	MUX Input B
4, 3	Vertical Sync Channel MUX Selection	1 0	Reserved; do not care
		0 1 0 1 0 0 0 1 1 0 0 1 1 0 0 0 1 1 0 0	Reserved; do not care
		0 0	MUX Input A
0.4	Harimantal Coma Channal MUIV Calastian	0 1	MUX Input B
2, 1	Horizontal Sync Channel MUX Selection	1 0	Reserved; do not care
		11	Reserved; do not care
0	LIA/ Supa Datha Disable Made	0	Disable H-Sync and V-Sync Channels
(LSB)	H/V Sync Paths Disable Mode	1	Enable H-Sync and V-Sync Channels

Bit (MSB) 7: Reserved; do not care.

Bit 6: Master Monitor Path Disable. Disables all monitor channels regardless of what is programmed into each register channel (1 to 3).

Bit 5: Master Buffer Path Disable. Disables all buffer channels regardless of what is programmed into each register channel (1 to 3).

Bits 4, 3: Selects the Input MUX channel for the Vertical Sync.

Bits 2, 1: Selects the Input MUX channel for the Horizontal Sync.

Bit 0 (LSB): Enables or disables the H-Sync and V-Sync Channels.



WRITE AND READ EXAMPLES

These examples illustrate the proper way to write to and read from the THS7347.

WRITING TO THE THS7347

An I²C master initiates a write operation to the THS7347 by generating a start condition (S) followed by the THS7347 I²C address, in MSB-first order, followed by a '0' to indicate a write cycle. After receiving an acknowledge from the THS7347, the master presents the subaddress (channel) it wants to write, consisting of one byte of data, MSB first. The THS7347 acknowledges the byte after completion of the transfer. Finally, the master presents the data it wants to write to the register (channel) and the THS7347 acknowledges the byte. The I²C master then terminates the write operation by generating a stop condition (P). Note that the THS7347 does not support multi-byte transfers. To write to all three channels (or registers), this procedure must be repeated for each register, one series at a time (that is, repeat steps 1 through 8 for each channel).

Step 1	0							
I ² C Start (Master) S								
Step 2	7	6	5	4	3	2	1	0
I ² C General Address (Master)	0	1	0	1	1	Х	Х	0

Where each X logic state is defined by I^2C -A1 and I^2C -A0 pins being tied to either V_{DD} or GND.

Step 3	9							
I ² C Acknowledge (Slave)	Α							
Step 4	7	6	5	4	3	2	1	0
I ² C Write Channel Address (Master)	0	0	0	0	0	Addr	Addr	Addr

Where *Addr* is determined by the values shown in Table 2.

Step 5	9
I ² C Acknowledge (Slave)	A

Step 6	7	6	5	4	3	2	1	0
I ² C Write Data (Master)	Data							

Where Data is determined by the values shown in Table 3.

Step 7	9
I ² C Acknowledge (Slave)	A

Step 8	0
I ² C Stop (Master)	P

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READING FROM THE THS7347

The read operation consists of two phases. The first phase is the address phase. In this phase, an I^2C master initiates a write operation to the THS7347 by generating a start condition (S) followed by the THS7347 I^2C address, in MSB-first order, followed by a '0' to indicate a write cycle. After receiving an acknowledge from the THS7347, the master presents the subaddress (channel) of the register it wants to read. After the cycle is acknowledged (A), the master terminates the cycle immediately by generating a stop condition (P).

The second phase is the data phase. In this phase, an I²C master initiates a read operation to the THS7347 by generating a start condition followed by the THS7347 I²C address, in MSB-first order, followed by a '1' to indicate a read cycle. After an acknowledge from the THS7347, the I²C master receives one byte of data from the THS7347. After the data byte has been transferred from the THS7347 to the master, the master generates a not-acknowledge (A) followed by a stop. As with the Write function, to read all channels, steps 1 through 11 must be repeated for each channel desired.

THS7347 Read Phase 1:

Step 1	0							
I ² C Start (Master)	S							
Step 2	7	6	5	4	3	2	1	0
I ² C General Address (Master)	0	1	0	1	1	Х	Х	0

Where each X logic state is defined by I^2C-A1 and I^2C-A0 pins being tied to either V_{DD} or GND.

Step 3	9							
I ² C Acknowledge (Slave)	А							
	•							
Step 4	7	6	5	4	3	2	1	0

Where *Addr* is determined by the values shown in Table 2.

Step 5	9	
I ² C Acknowledge (Slave)	A	
Step 6	0	
I ² C Start (Master)	Р	



THS7347 Read Phase 2:

Step 7	0							
I ² C Start (Master)	S							
	·							
Step 8	7	6	5	4	3	2	1	0
I ² C General Address (Master)	0	1	0	1	1	Х	Х	1

Where each X Logic state is defined by I^2C-A1 and I^2C-A0 pins being tied to either V_{DD} or GND.

Step 9	9							
I ² C Acknowledge (Slave)	Α							
Step 10	7	6	5	4	3	2	1	0
I ² C Read Data (Slave)		Data						

Where Data is determined by the logic values contained in the Channel Register.

Step 11	9
I ² C Not-Acknowledge (Master)	Ā

Step 12	0
I ² C Stop (Master)	P



REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	nanges from Revision A (September 2008) to Revision B	Page
•	Changed first DC Performance, <i>Bias output voltage, Buffer output</i> parameter row +25°C, 0°C to +70°C, and –40°C to +85°C specifications in 3.3-V Electrical Characteristics table	3
•	Changed first DC Performance, <i>Bias output voltage, Monitor output</i> parameter row +25°C, 0°C to +70°C, and -40°C to +85°C specifications in 3.3-V Electrical Characteristics table	
•	Changed DC Performance, Sync tip clamp voltage, Buffer output parameter +25°C, 0°C to +70°C, and -40°C to +85°C specifications in 3.3-V Electrical Characteristics table	3
•	Changed first DC Performance, <i>Bias output voltage, Buffer output</i> parameter row +25°C, 0°C to +70°C, and -40°C to +85°C specifications in 5-V Electrical Characteristics table	6
•	Changed first DC Performance, <i>Bias output voltage, Monitor output</i> parameter row +25°C, 0°C to +70°C, and -40°C to +85°C specifications in 5-V Electrical Characteristics table	
•	Changed DC Performance, Sync tip clamp voltage, Buffer output parameter +25°C, 0°C to +70°C, and –40°C to +85°C specifications in 5-V Electrical Characteristics table	6
CI	nanges from Original (May 2007) to Revision A	Page
•	Added Digital Characteristics section to 3.3-V Electrical Characteristics table	3
•	Added Digital Characteristics section to 5-V Electrical Characteristics table	6

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
THS7347IPHP	Active	Production	HTQFP (PHP) 48	250 JEDEC TRAY (10+1)	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	THS7347
THS7347IPHP.B	Active	Production	HTQFP (PHP) 48	250 JEDEC TRAY (10+1)	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	THS7347
THS7347IPHPG4	Active	Production	HTQFP (PHP) 48	250 JEDEC TRAY (10+1)	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	THS7347
THS7347IPHPR	Active	Production	HTQFP (PHP) 48	1000 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	THS7347
THS7347IPHPR.B	Active	Production	HTQFP (PHP) 48	1000 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 85	THS7347

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No. RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

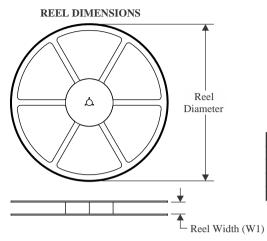
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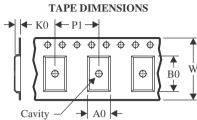
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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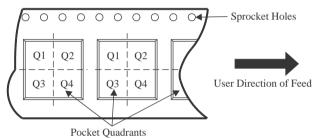
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

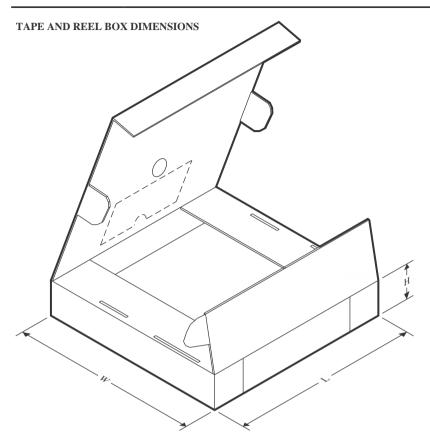


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THS7347IPHPR	HTQFP	PHP	48	1000	330.0	16.4	9.6	9.6	1.5	12.0	16.0	Q2

PACKAGE MATERIALS INFORMATION

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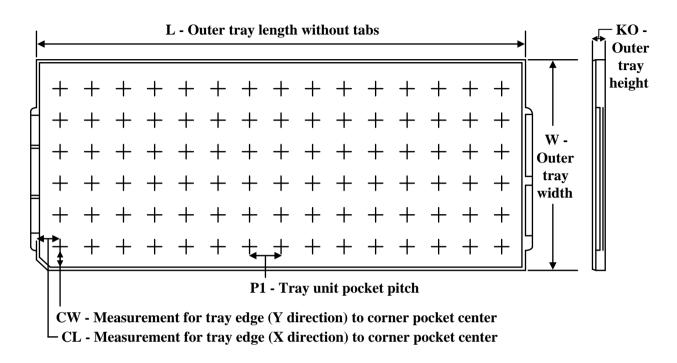
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
THS7347IPHPR	HTQFP	PHP	48	1000	350.0	350.0	43.0	



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TRAY



Chamfer on Tray corner indicates Pin 1 orientation of packed units.

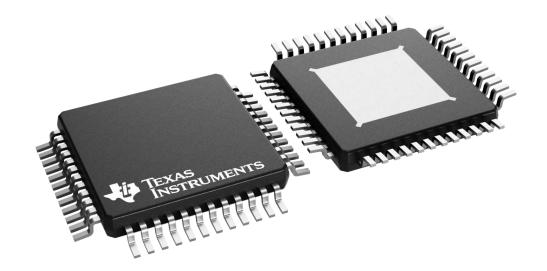
*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	Unit array matrix	Max temperature (°C)	L (mm)	W (mm)	Κ0 (μm)	P1 (mm)	CL (mm)	CW (mm)
THS7347IPHP	PHP	HTQFP	48	250	10 x 25	150	315	135.9	7620	12.2	11.1	11.25
THS7347IPHP.B	PHP	HTQFP	48	250	10 x 25	150	315	135.9	7620	12.2	11.1	11.25
THS7347IPHPG4	PHP	HTQFP	48	250	10 x 25	150	315	135.9	7620	12.2	11.1	11.25

7 x 7, 0.5 mm pitch

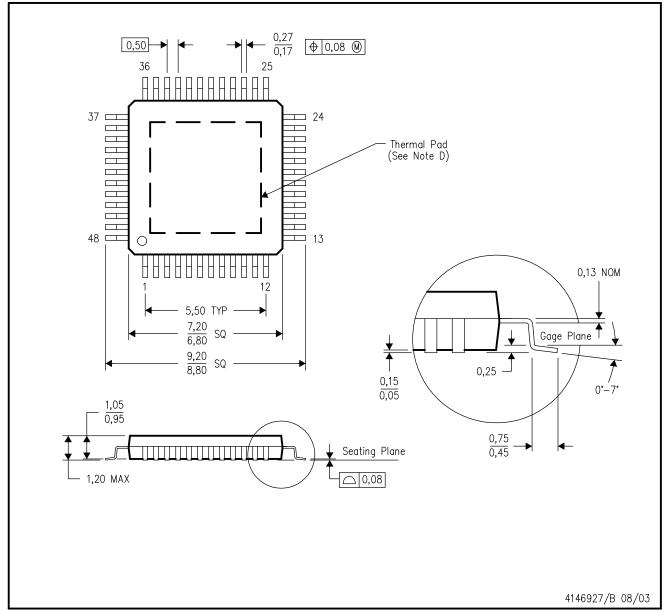
QUAD FLATPACK

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



PHP (S-PQFP-G48)

PowerPAD™ PLASTIC QUAD FLATPACK



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com www.ti.com.
- E. Falls within JEDEC MS-026

PowerPAD is a trademark of Texas Instruments.



PHP (S-PQFP-G48)

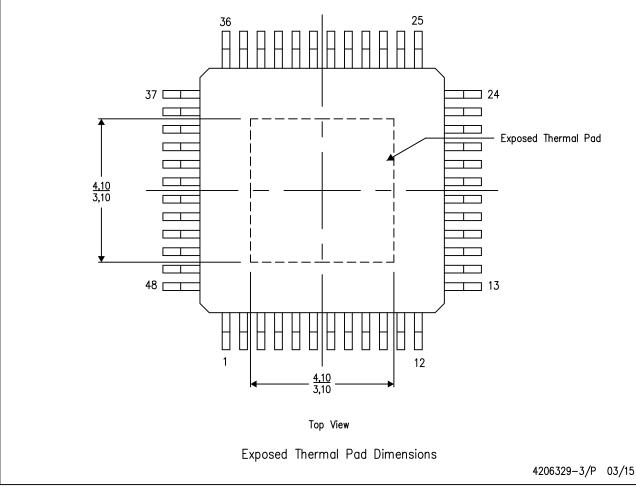
PowerPAD™ PLASTIC QUAD FLATPACK

THERMAL INFORMATION

This PowerPAD $^{\text{TM}}$ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



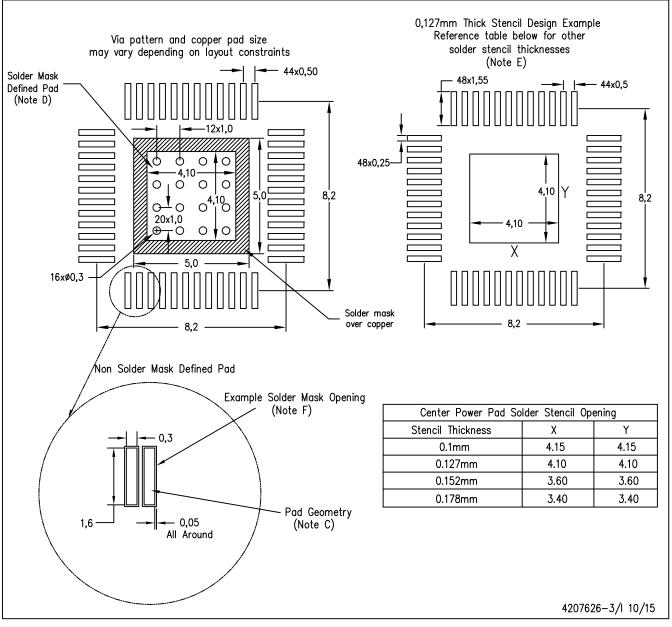
NOTE: A. All linear dimensions are in millimeters

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PHP (S-PQFP-G48)

PowerPAD™ PLASTIC QUAD FLATPACK



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting options for vias placed in the thermal pad.

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